# Insulated Ultrafast Rectifier Module, 130 A



PRIMARY CHARACTERISTICS						
V <sub>R</sub>	200 V					
$I_{F(AV)}$ per module at $T_C = 126 \ ^{\circ}C$	130 A					
t <sub>rr</sub>	32 ns					
Туре	Modules - diode FRED Pt®					
Package	SOT-227					

#### **FEATURES**

- Two fully independent diodes
- Fully insulated package
- RoHS • Ultrafast, soft reverse recovery, with high COMPLIANT operation junction temperature (T<sub>.1</sub> max. = 175 °C)
- Low forward voltage drop
- · Optimized for power conversion: welding and industrial SMPS applications
- · Easy to use and parallel
- Industry standard outline
- UL approved file E78996
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **DESCRIPTION / APPLICATIONS**

The VS-UFB130FA20 insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The diodes structure, and its life time control, provide an ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V <sub>R</sub>		200	V	
Continuous forward current per diode	l <sub>F</sub>	T <sub>C</sub> = 132 °C	65	•	
Single pulse forward current per diode	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	890	A	
Maximum power dissipation per module	PD	T <sub>C</sub> = 132 °C	119	W	
RMS isolation voltage	V <sub>ISOL</sub>	Any terminal to case, t = 1 min	2500	V	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	







www.vishay.com

# Vishay Semiconductors

<b>ELECTRICAL SPECIFICATIONS PER DIODE</b> ( $T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA	200	-	-	
	V	I <sub>F</sub> = 60 A	-	0.96	1.13	V
Forward voltage	V <sub>FM</sub>	I <sub>F</sub> = 60 A, T <sub>J</sub> = 175 °C	-	0.75	0.89	
Reverse leakage current I <sub>RM</sub>		V <sub>R</sub> = V <sub>R</sub> rated	-	2	50	μA
	$T_J = 175 \text{ °C}, V_R = V_R \text{ rated}$	-	-	1	mA	
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	105	-	pF

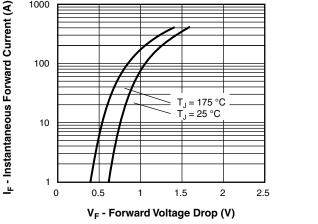
<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	32	-	
Reverse recovery time		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 50 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 100 V	-	42	-	ns
		T <sub>J</sub> = 125 °C		-	68	-	
Peak recovery current I <sub>RRM</sub>		T <sub>J</sub> = 25 °C		-	4.0	-	A
	IRRM	T <sub>J</sub> = 125 °C		-	9.0	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	82	-	nC
		T <sub>J</sub> = 125 °C		-	295	-	

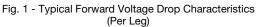
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single leg conducting	В		-	-	0.72	
Junction to case, both leg conducting	R <sub>thJC</sub>		-	-	0.36	°C/W
Case to heatsink	R <sub>thCS</sub>	Flat, greased surface	-	0.10	-	
Weight			-	30	-	g
Mounting torque	Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)	
		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)
Case style				S	OT-227	

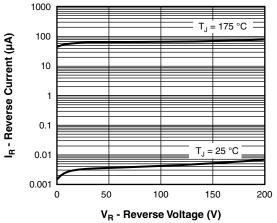
# VS-UFB130FA20

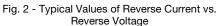
## **Vishay Semiconductors**











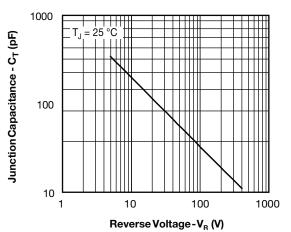
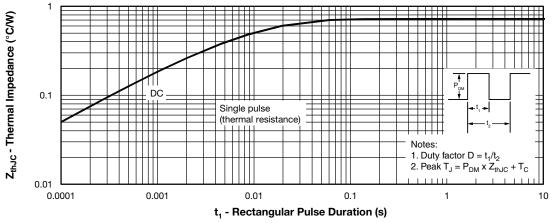
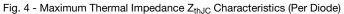


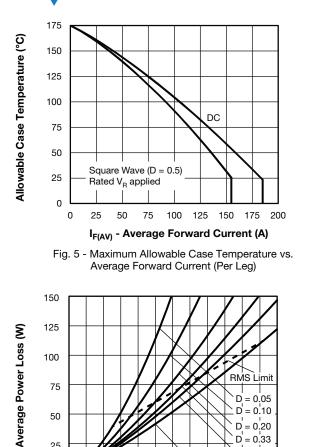
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



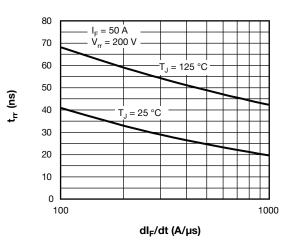


 Revision: 18-Sep-2018
 3
 Document Number: 93606

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



www.vishay.com





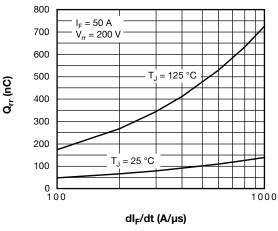


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

75

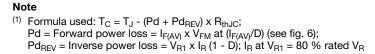
50

25

0

0

SHA



DC

10 20 30 40 50 60 70 80 90 100 110 120

I<sub>F(AV)</sub> - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics (Per Leg)

RMS Limit

D = 0.05

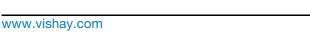
D = 0.10

D = 0.20

D = 0.33

D = 0.50

## VS-UFB130FA20



## **Vishay Semiconductors**

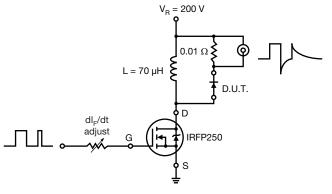
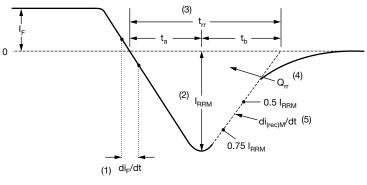


Fig. 9 - Reverse Recovery Parameter Test Circuit



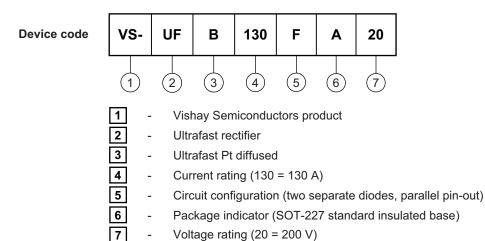
- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (4)  ${\rm Q}_{\rm rr}$  area under curve defined by  ${\rm t}_{\rm rr}$  and  ${\rm I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

- (2)  $I_{\text{RRM}}$  peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.
- (5)  $di_{(rec)M}/dt$  peak rate of change of current during  $t_b$  portion of  $t_{rr}$
- Fig. 10 Reverse Recovery Waveform and Definitions



#### **ORDERING INFORMATION TABLE**



**CIRCUIT CONFIGURATION** CIRCUIT CIRCUIT **CIRCUIT DRAWING CONFIGURATION CODE** Lead Assignment 4 3 O 3  $4 \cap$ Two separate diodes, F parallel pin-out () 10  $\cap 2$ 2 1

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95423				
Packaging information	www.vishay.com/doc?95425				



SOT-227 Generation 2

#### **DIMENSIONS** in millimeters (inches)



#### Note

• Controlling dimension: millimeter



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

 70HFR40
 RL252-TP
 150KR30A
 1N5397
 NTE5841
 NTE6038
 SCF5000
 1N4002G
 1N4005-TR
 JANS1N6640US
 481235F

 RRE02VS6SGTR
 067907F
 MS306
 70HF40
 T110HF60
 T85HFL60S02
 US2JFL-TP
 A1N5404G-G
 CRS04(T5L,TEMQ)
 ACGRA4007-HF

 ACGRB207-HF
 CLH03(TE16L,Q)
 ACGRC307-HF
 ACEFC304-HF
 NTE6356
 NTE6359
 NTE6002
 NTE6023
 NTE6039
 NTE6077

 85HFR60
 40HFR60
 1N1186RA
 70HF120
 85HFR80
 D126A45C
 SCF7500
 D251N08B
 SCHJ22.5K
 SM100
 SCPA2
 SCH10000
 SDHD5K

 VS-12FL100S10
 ACGRA4001-HF
 D1821SH45T PR
 D1251S45T
 NTE5990
 NTE6358